REV LTR	DESCRIPTION	DATE	APPVD.
-	Orig. Release	6/22/09	RBT
А	Corrected P/N on Pages 1 and 2	5/08/14	RBT
В	Revised per ECN 2015-1	9/12/15	RBT
С	Revised per ECN 2016-1	9/18/16	RBT

FTL2 Series LVDS/LVPECL output, OSCILLATORS FOR SPACE APPLICATIONS 0.75MHz to 1400MHz

(5 x 7 mm, SMD, 2.5 V)

(Refer to Page 5 for Models with Reduced Screening & QCI)

- 1. SCOPE: FTL2 series , LVDS/LVPECL output, high reliability hybrid microcircuit crystal oscillators are designed, produced and tested by Frequency Technology, Inc. as MIL-PRF-55310, Class "S" equivalent devices for use in advanced military, avionics and space applications. These devices are of hybrid microcircuit technology conforming to MIL-PRF-55310, Type 1, Class 2 oscillators.
- 2. APPLICABLE DOCUMENTS:

MIL-PRF-55310EOscillator, Crystal Controlled, General Specifications forMIL-PRF-38534GHybrid Microcircuits, General Specifications forMIL-STD-883ETest Methods and Procedures for Microelectronics

- 3. REQUIREMENTS:
- 3.1 General: The individual item requirements shall be as specified herein.
- 3.2 Package: Ceramic, 90% Min. AL_2O_3 . Thermal Resistance, θ_{JC} : 50 °C / Watt.
- 3.2.1 Termination Finish: 1.3 μm minimum gold plate over 2.0 μm minimum nickel plate. Hot Solder tinning with Sn60/Pb40 solder per MIL-PRF-55310 is optional at an additional cost.
- 3.2.2 Weight: 0.30 Gms Max.
- 3.2.3 Reflow Soldering: Reflow soldering at 260 °C for 10 seconds shall not degrade the performance.
- 3.3 Hermeticity: Resistance welded, hermetically sealed, leak rate of $1(10)^{-8}$ atm-cc/s Max.
- 3.4. Marking: As a minimum, the parts shall be marked with Fre-techP/N and date code
- 3.5 Absolute Maximum Ratings: Unless otherwise specified, absolute maximum ratings shall be as follows:

Supply Voltage	-0.5 to +4.0 VDC
Operating Free-Air Temperature Range	-55°C to +125°C
Storage Temperature	-65°C to +125°C

- 3.6 Electrical Characteristics: See Table I
- 3.6.1 Total Dose Radiation: Hybrid Microcircuit Crystal Oscillators shall be capable of meeting the electrical characteristics of Para. 3.6 after being exposed to total ionizing dose radiation of 100 krads as per MIL-STD-883, method 1019.
- 3.7 Hybrid Elements:
- 3.7.1 Quartz Crystals: High grade cultured quartz crystal shall be used. As an option, Fre-tech will use premium Q swept quartz crystal at an additional charge, refer to part numbering example in paragraph 6 to specify swept quartz crystal. Crystal element evaluation shall be in accordance with MIL-PRF-55310.
- 3.7.2 Crystal Mounting: Crystal element shall be mounted at 4 points in such a manner as to provide adequate ruggedness and performance under extreme environments specified herein.

- 3.7.3 Passive Elements: Established Reliability (ER) QPL components, failure level R minimum shall be used or element lot evaluation shall be as per MIL-PRF-55310, class S, or MIL-PRF-38534, Appendix C, Class K as applicable.
- 3.7.4 Microcircuit die shall be from lots that have passed the element evaluation per MIL-PRF-55310, Appendix B, Level S, except testing per Subgroup 5 is omitted. Subgroup 5 testing is circuit configuration dependent, therefore, it is more effectively performed at the oscillator level as explained in Paragraph 3.7.4 herein.
- 3.7.5 For Output Frequency up to 90 MHz, microcircuit die used in the oscillator shall be from NSC/FC 54ACT family and must be from wafer lot that has been successfully tested in the oscillator for ionizing radiation of up to100 krads Fre-tech has also performed SET & SEL testing on the microcircuit die. Test reports are available on request. For output frequencies above 90 MHz, the microcircuit die shall be from 0,8 μm BiCMOS Si family and must be from wafer lots that have been successfully tested in the oscillator for ionizing radiation of up to 100Krads and is known to be Single Event Latch-up immune for LET of up to 95 Mev-cm²/mg.
- 3.7.6 Workmanship, Rework and Process controls shall be in accordance with the requirements of MIL-PRF-55310.
- 3.7.7 Lot Traceability: Production lot for these oscillators shall be homogenous. Each element used in the production lot shall be traceable to a single lot. Swept quartz shall be traceable to the quartz bar, and its applicable processing details.
- 4. Quality Assurance Provisions: The quality assurance provisions shall be per MIL-PRF-55310, except as specified herein.
- 4.1 100% Screening: The 100% screening shall be performed as per Table II. PDA requirements for nondestructive bond pull and burn-in shall be as specified below.
- 4.2 PDA for Nondestruct Bond Pull: Unless otherwise specified, PDA shall be 2% of total number of wires or 1 wire whichever is greater.
- 4.3 PDA for Burn-in: Unless otherwise specified, PDA for burn-in shall be 2% or 1 oscillator whichever is greater and shall be applicable to +23 °C and/or +25 °C static tests only. In addition Delta Calculation shall be performed after Burn-in and shall count for PDA. All measured values for Delta Calculation shall be recorded. Parts that exceed the specified delta limits shall be rejected and be counted for PDA. Delta Calculation shall be performed at 3.3 VDC for the following parameters:

Input Current	10% change Maximum
Output High Level	10% change Maximum
Output Low Level	0.1V change Maximum

- 4.4 Group A inspection shall be in accordance with MIL-PRF-55310 for product level S.
- 4.5 Group B inspection (30 day aging) shall be in accordance with MIL-PRF-55310 for product level S. In order to expedite delivery, by customer request, the aging test can be ended after 15 days if the amount of frequency aging is less than 50% of the 30 day specification limit.
- 4.6 Oscillators shall be capable of meeting group C inspection per MIL-PRF-55310. Generic group C inspection data on similar parts may be used to satisfy this requirement. When specified by the Customer, Fre-tech will perform Group C testing at an additional charge.

4.7 Inspection and Test Data: Unless otherwise specified in the purchase order, the following Inspection and test data documentation shall be supplied with the parts.

Certificate of Conformance Summary of Class "S" screening Test Results PDA Calculations for Non-Destruct Bond Pull and Burn-in Summary of Elements Lot Traceability Electrical Tests before and after Burn-in Group A Inspection Summary Group B (30 day Aging) Data Radiographic Inspection Certificate

4.8 The following test and inspection options are available at customer request.

Customer Source Inspection for Pre-Cap and Final Group C Inspection per MIL-PRF-55310 on 4 or 8 units DPA (Destructive Physical Analysis) Life Test per MIL-STD-883, Method 1005, 1000 Hrs. at +125 °C MIL-PRF-38534, Group B Inspection MIL-PRF-38534, Group C Inspection

5.0 Preservation, Packaging and Packing: The oscillators shall be clean, dry and packaged in a manner to provide adequate protection against electrostatic discharge, corrosion, deterioration and physical damage during shipment.

6.0 Part Numbering Example:

FTL2 – W	5	V / 200
Output Logic	Frequency/ Temperature Stability	Screening Level Frequency(MHz)
W = LVDS $P = LVPECL$	$1 = 100 \text{ ppm over } -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $2 = 50 \text{ ppm over } -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $3 = 25 \text{ ppm over } -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $4 = 100 \text{ ppm over } -55^{\circ}\text{C to } +125^{\circ}\text{C}$ $5 = 50 \text{ ppm over } -55^{\circ}\text{C to } +125^{\circ}\text{C}$ $6 = 20 \text{ ppm over } -20^{\circ}\text{C to } +70^{\circ}\text{C}$	N = No Screening I = Industrial Std M = MIL-STD-883 B = MIL-PRF-55310D Class B S = MIL-PRF-55310D Class S V = MIL-PRF-55310D Class S, 50krad(Si) total dose R = MIL-PRF-55310D Class S, 100krad(Si) total dose

* Overall Frequency Accuracy includes effects of Operating Temperature, Supply Voltage, Load variations and 10 year aging

P/N Example: FTL2-W5V- 200.000 MHz = 200.000 MHz, Class "V" Oscillator, <u>+</u> 50 PPM Overall Frequency Accuracy over an operating temperature range of -55 °C to +125 °C, 2.5V,LVDS output

NOTE: Besides **Class R and Class V**, the following additional models are available for applications that can accommodate reduced level of screening and quality conformance inspection:

Class S : Class S is same as Class R and ClassV except as follows:

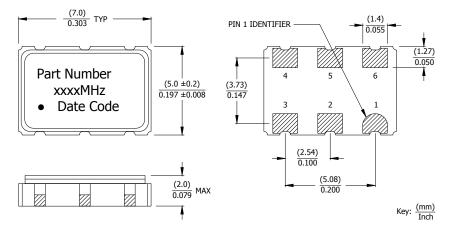
Group A inspection is per MIL-PRF-55310, Class B Group B inspection (30 day aging) per MIL-PRF-55310 is not applicable

Class B : Class B uses the same design and elements as Class S except as follows:

100% screening is as per Table III herein PDA for Burn-in is 10% or 1 unit whichever is greater Delta measurements of paragraph 4.3 are not applicable Group A inspection is as per MIL-PRF-55310, Class B Group B inspection (30 day aging) per MIL-PRF-55310 is not applicable

- Class M : Class M is same as Class B except as follows: Active and Passive Elements are as per MIL-PRF-55310, Class B. Microcircuit die is similar to the one used in Model FTH4XXB but is not from radiation tested wafer lot.
- Class I/N : Class I and Class N is a form, fit and function equivalent prototype of Class R to Calss M Prototypes may use and industrial and commercial grade elements and are not screened. Quality Conformance inspection is not applicable.

PACKAGE DRAWING



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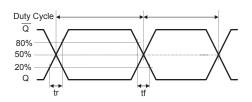
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Key: $\frac{[mm]}{Inch}$

Pin connections

Pin #	Connection			
1	N/C			
2	N/C			
3	Case, GND			
4	Output			
5	Output			
6	Supply Voltage			

Output Waveform



Test Circuit and Waveform

SUGGESTED SOLDER PAD LAYOUT

C BYPASS

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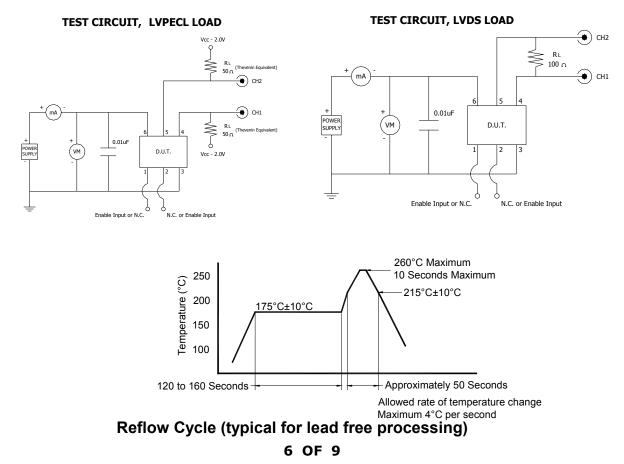
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	-	TABLE I	- Electrical Characteristic	<u>25</u>			
	PARAMETER	SYMBOL	CONDITIONS	MIN	ГҮР	MAX	UNIT
	Maximum Su pply Voltage	V _{CC}	-	-0.5	-	4.0	V
	Stora ge Tem perature	T _{STG}	-	-55	-	125	°C
sunu	Fre quenc y Ran ge LVPECL and LVDS	f_{O}	-	0.75		1400	MHz
Absolute Maximums	Frequency Stability	$\Delta f/f_{0}$	-	-	-	20, 25, 50 or 100	$\pm \text{ppm}$
Absolu	Operatin g Tem perature Commercial Industrial Military	T _A	-	-20 -40 -55	25	70 85 125	°C
	Supply Voltage(Optional 1.8V)	V _{CC}	± 5 %	2.38	2.5	2.63	V
	Supply Current LVPECL LVDS	I _{CC}	Maximum Load	-		130 110	mA
	Start U p Time	Ts	Application of V _{CC}	-	3	10	ms
	Phase Jitter	tjrms	Bandwidth 12 kHz - 20 MHz	-	-	1	ps RMS
	Period Jitter	pjrms	-	-	-	5	ps RMS
	Enable Function Enable In put Voltage Disable In put Voltage	$V_{IH} = V_{II}$	Standby Pin 1 or Pin 2 Logic '1', Output Enabled Pin 1 or Pin 2 Logic '0', Output Disabled	0.7*V _{CC}	-	0.3*V _{CC}	v
	Disable Current	I_{IL}	Pin 1 or Pin 2 Lo gic '1', Out put Disabled	-	-	20	uA
	Enable Time	T _{PLZ}	Pin 1 or Pin 2 Lo gic '1'	-	-	5	ns
ers	LVPECL WAVEFORM						
net	Out put Load	R _L	-	-	50	-	Ohms
araı	Out put Dut y Cycle	SYM	@ V _{CC} - 1.3V	40	-	60	%
Electrical and Waveform Parameters	Out put Volta ge Levels Logic 'l' Level Logic '0' Level	V _{OH} V _{OL}	PECL Load PECL Load	V _{CC} - 1.025V -	-	- V _{CC} - 1.62V	v
I and W	Rise and Fall Time $f_{\Omega} < 100 \text{ MHz}$ $f_{\Omega} > 100 \text{ MHz}$	T _R , T _F	@ 20% - 80% Levels	-	0.8 0.5	2.5 2.0	ns
nicé	LVDS WAVEFORM						
lect	Out put Load	R _L	Between Out puts	-	100	-	Ohms
Ē	Out put Dut y Cycle	SYM	@ 1.25V	40	-	60	%
	Differential Out put Voltage	V _{OD}	RL = 100 Ohms	247	350	454	mV
	Differential Out put Error	-	-	-	-	50	mV
	Offset Volta ge	Vos	LVDS Load	1.125	1.25	1.375	V
	Offset Error	-	-	-	-	50	mV
	Out put Volta ge Levels Logic 'l' Level Logic '0' Level	V _{OH} V _{OL}	LVDS Load LVDS Load	- 0.8	1.40 1.1	1.7	v
	Rise and Fall Time $f_{\Omega} < 100 \text{ MHz}$ $f_{\Omega} > 100 \text{ MHz}$	T _R , T _F	@ 20% - 80% Levels	-	0.8 0.5	2.5 2.0	ns

Jitter Specifications

PARAMETER	CONDITIONS	FREQ	MIN	ТҮР	MAX	UNIT
		25 MHz		2.0		
Period Jitter (RMS)	Sample size > 10,000 cycles	155.52 MHz		4.3		
		622.08 MHz		5.0		
Period Jitter (pk-pk)		25 MHz		20.0		
	Sample size > 10,000 cycles	155.52 MHz		35.0		
		622.08 MHz		45.0		psec
		25 MHz		1.0		
Phase Jitter (RMS)	Integrated	77.76 MHz		0.5		
	12 kHz to 20 MHz	155.52 MHz		0.3		
		622.08 MHz		0.1		

Phase Noise Specifications

PARAMETER	FREQ	10 Hz	100 Hz	1 kHz	10 kHz	100 kHz
	25 MHz	-73	-103	-133	-147	153
Phase Noise, dBc/Hz (typical)	77.76 MHz	-66	-96	-120	-129	-126
	155.52 MHz	-63	-93	-117	-126	-123
	622.08 MHz	-52	-83	-105	-113	-110

Contact Fre-tech Engineering for any other special requirements.

1/ Overall Frequency Accuracy includes calibration tolerance, frequency change due to Operating Temperature, Supply Voltage and Load variations and 10 year aging.

Table II - Class R/V/S , Screening (100%)

Test - Inspection	Test Method – Condition			
Nondestructive Bond Pull	MIL-STD-883, Method 2023			
Internal Visual	MIL-STD-883, Method 2017, Level S			
Stabilization Bake (Prior to Seal) <u>1</u> /	MIL-STD-883, Method 1008, Condition C (+150 °C), 48 hours minimum			
Thermal Shock	MIL-STD-883, Method 1011, Condition A			
Temperature Cycling	MIL-STD-883, Method 1010, Condition B			
Constant Acceleration	MIL-STD-883, Method 2001, Condition A Y ₁ axis only (5000 G)			
Seal (Fine and Gross Leak)	MIL-PRF-55310, Para. 4.8.2.2.2			
Particle Impact Noise Detection (PIND)	MIL-STD-883, Method 2020, Condition A			
Radiographic Inspection	MIL-STD-883, Method 2012, Class S			
Electrical Tests: Record all measurements.	Nominal Supply Voltage, Specified load, +23 $^{\circ}$ C			
Input Current Output Frequency Output Voltage Levels Output Rise & Fall Times Output Duty Cycle	MIL-PRF-55310, Para. 4.8.5 MIL-PRF-55310, Para. 4.8.6 MIL-PRF-55310, Para. 4.8.21.3 MIL-PRF-55310, Para. 4.8.22 MIL-PRF-55310, Para. 4.8.23			
Burn-in (load)	+125 °C, Nominal Supply Voltage and Burn-in load, 320 Hours Minimum			
Electrical Tests: Record all measurements.	Nominal and Extreme Supply Voltages, Specified load, +23 °C and operating temperature extremes,			
Input Current Output Frequency Output Voltage Levels Output Rise & Fall Times Output Duty Cycle	MIL-PRF-55310, Para. 4.8.5 MIL-PRF-55310, Para. 4.8.6 MIL-PRF-55310, Para. 4.8.21.3 MIL-PRF-55310, Para. 4.8.22 MIL-PRF-55310, Para. 4.8.23			

<u>1</u>/ Vacuum bake and maintain oscillators in dry nitrogen per MIL-PRF-55310.

Table III - <u>Class B/M Screening (100%)</u>				
Test - Inspection	Test Method – Condition			
Nondestructive Bond Pull	MIL-STD-883, Method 2023			
Internal Visual	MIL-STD-883, Method 2017, Level B			
Stabilization Bake (Prior to Seal) $1/$	MIL-STD-883, Method 1008, Condition C (+150 °C), 24 hours minimum			
Temperature Cycling	MIL-STD-883, Method 1010, Condition B			
Constant Acceleration	MIL-STD-883, Method 2001, Condition A Y_1 axis only (5000 G)			
Seal (Fine and Gross Leak)	MIL-PRF-55310, Para. 4.8.2.2.2			
Particle Impact Noise Detection (PIND)	MIL-STD-883, Method 2020, Condition A			
Electrical Tests: Input Current Output Frequency Output Voltage Levels Output Rise & Fall Times Output Duty Cycle	Nominal Supply Voltage, Specified load, +23 °C Verify all parameters MIL-PRF-55310, Para. 4.8.5 MIL-PRF-55310, Para. 4.8.6 MIL-PRF-55310, Para. 4.8.21.3 MIL-PRF-55310, Para. 4.8.22 MIL-PRF-55310, Para. 4.8.23			
Burn-in (load)	+125 °C, Nominal Supply Voltage and Burn-in load, 160 Hours Minimum			
Electrical Tests: Input Current Output Frequency Output Voltage Levels Output Rise & Fall Times Output Duty Cycle	Nominal Supply Voltage, Specified load, +23 °C and verify frequency at temperature extremes. MIL-PRF-55310, Para. 4.8.5 MIL-PRF-55310, Para. 4.8.6 MIL-PRF-55310, Para. 4.8.21.3 MIL-PRF-55310, Para. 4.8.22 MIL-PRF-55310, Para. 4.8.23			

<u>1</u>/ Vacuum bake and maintain oscillators in dry nitrogen per MIL-PRF-55310.